

TYPES SN54LS681, SN74LS681 4-BIT PARALLEL BINARY ACCUMULATORS

D2422, JANUARY 1981—REVISED APRIL 1985

- Full 4-Bit Binary Accumulator in a Single 20-Pin Package
- Contains Two Synchronous Registers:
Word A
Word B Shift/Accumulator
- 16 Arithmetic Operations Including
B Minus A and A Minus B
- 16 Logic-Mode Operations
- Expandable to Handle N-Bit Words
with Full Carry Look-Ahead
- Bus Driving I/O Ports

description

These low-power Schottky IC's integrate a high-speed arithmetic logic unit (ALU) complete with word A and word B registers on a single chip. The ALU performs 16 arithmetic and 16 logic functions (see Tables 1 and 2). Full carry look-ahead is provided for fast carry of four-bit words. The carry input (C_n) and propagate and generate outputs (\bar{P} and \bar{G}) are provided for direct use with SN54S182/SN74S182 carry look-ahead generators for optimum performance with longer words.

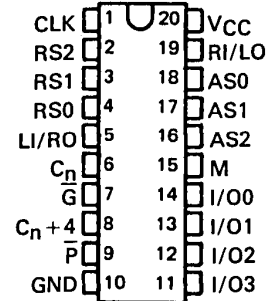
The A and B registers are controlled by three inputs (RS0, RS1, and RS2). These pins define eight distinct register modes (see Table 3). The A register is a simple storage register while the B register is a combination storage/shift/accumulator register. The contents of the A and B registers provide the A and B words for the ALU.

Four I/O ports (I/O 0 thru I/O 3) are provided for parallel loading of word A and/or word B into their respective registers. These same ports also serve as bus driving outputs for the ALU/accumulator results (Fj). Two additional I/O ports (RI/LO and LI/RO) are provided to allow expansion of the accumulator for words greater than four bits in length.

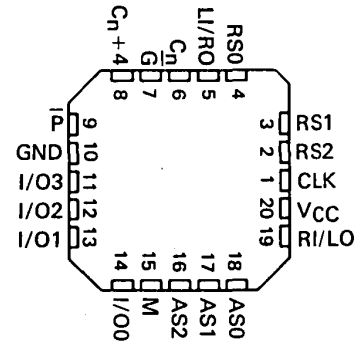
The A or B register can be parallel loaded from the four I/O ports. The B register can also be parallel loaded from the ALU as an accumulator register and in addition, the B register can be serially loaded from either the RI/LO or the LI/RO ports.

The SN54LS681 is characterized for operation over the full military temperature range from -55°C to 125°C . The SN74LS681 is characterized for operation from 0°C to 70°C .

SN54LS681 ... J PACKAGE
SN74LS681 ... DW, J OR N PACKAGE
(TOP VIEW)



SN54LS681 ... FK PACKAGE
SN74LS681 ... FN PACKAGE
(TOP VIEW)



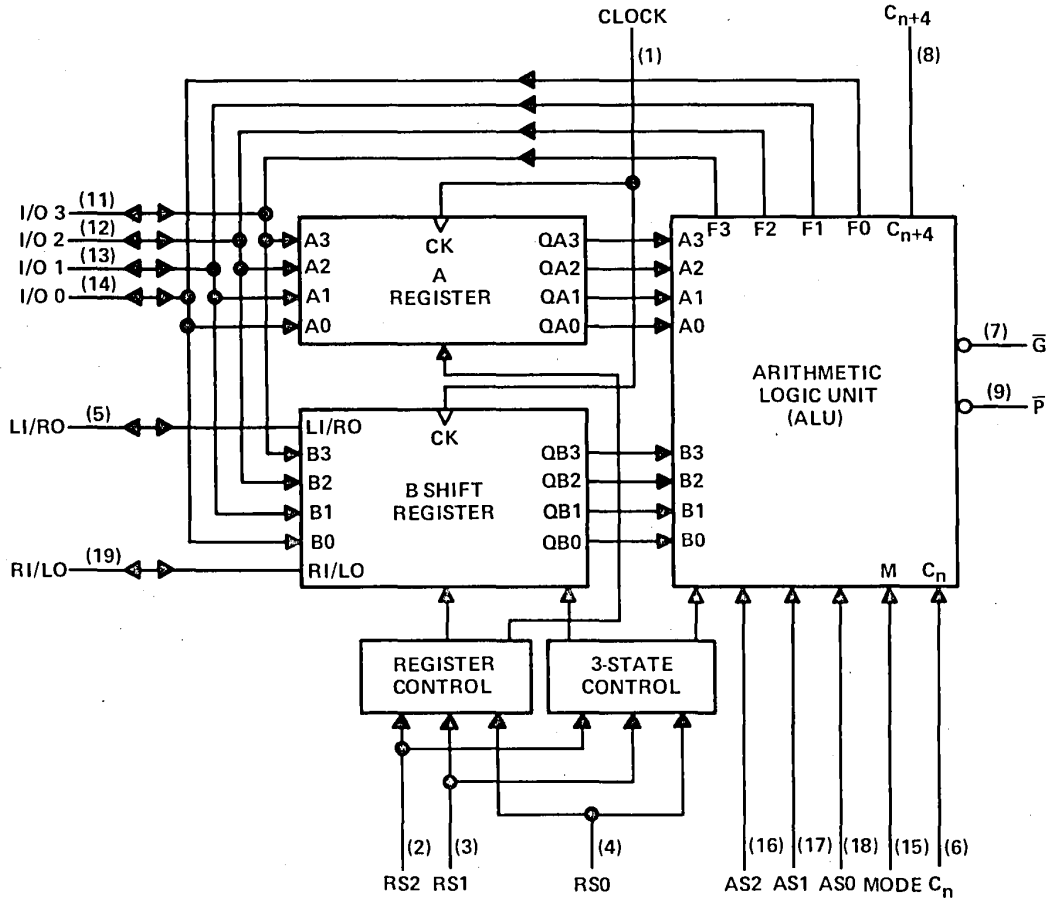
PRODUCTION DATA
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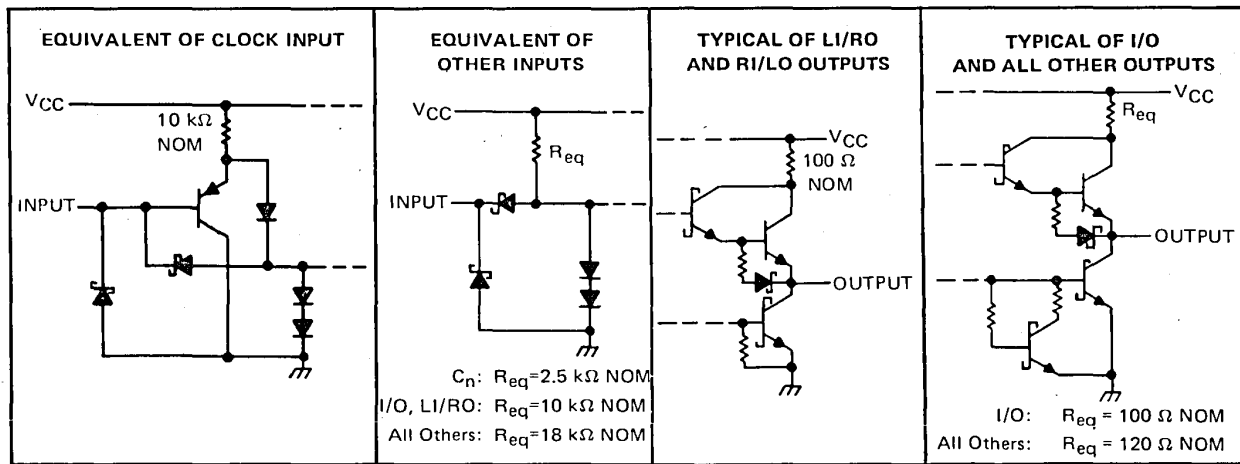
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TYPES SN54LS681, SN74LS681
4-BIT PARALLEL BINARY ACCUMULATORS

functional block diagram



schematics of inputs and outputs



3

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TYPES SN54LS681, SN74LS681 4-BIT PARALLEL BINARY ACCUMULATORS

FUNCTION TABLES

TABLE 1 – ARITHMETIC FUNCTIONS

Mode Control (M) = Low

ALU SELECTION			ACTIVE-HIGH DATA	
			C _n = H (with carry)	C _n = L (no carry)
AS2	AS1	AS0		
L	L	L	F _j = L	F _j = H
L	L	H	F = B MINUS A	F = B MINUS A MINUS 1
L	H	L	F = A MINUS B	F = A MINUS B MINUS 1
L	H	H	F = A PLUS B PLUS 1	F = A PLUS B
H	L	L	F = B PLUS 1	F _j = B _j
H	L	H	F = \bar{B} PLUS 1	F _j = \bar{B}_j
H	H	L	F = A PLUS 1	F _j = A _j
H	H	H	F = \bar{A} PLUS 1	F _j = \bar{A}_j

TABLE 2 – LOGIC FUNCTIONS

Mode Control (M) = High

ALU SELECTION			ACTIVE-HIGH DATA	
			C _n = H (with carry)	C _n = L (no carry)
AS2	AS1	AS0		
L	L	L	F ₀ = H, F ₁ = F ₂ = F ₃ = L	F _j = L
L	L	H	F _j = A _j ⊕ B _j PLUS 1	F _j = $\overline{A_j \oplus B_j}$
L	H	L	F _j = $\overline{A_j \oplus B_j}$ PLUS 1	F _j = A _j ⊕ B _j
L	H	H	F _j = L	F _j = H
H	L	L	F _j = A _j B _j PLUS 1	F _j = A _j B _j
H	L	H	F _j = $\overline{A_j + B_j}$ PLUS 1	F _j = $\overline{A_j + B_j}$
H	H	L	F _j = $\overline{A_j B_j}$ PLUS 1	F _j = $\overline{A_j B_j}$
H	H	H	F _j = A _j + B _j PLUS 1	F _j = A _j + B _j

TABLE 3 – REGISTER FUNCTIONS

FUNCTION	INPUTS BEFORE L TO H CLOCK TRANSITION									INTERNAL OUTPUTS AFTER L TO H CLOCK TRANSITION													
	REGISTER SELECTION			DATA INPUTS						A REGISTER				B SHIFT REGISTER						ALU			
	RS2	RS1	RS0	LI/RO	I/O 3	I/O 2	I/O 1	I/O 0	RI/LO	QA3	QA2	QA1	QA0	LI/RO	QB3	QB2	QB1	QB0	RI/LO	F3	F2	F1	F0
ACCUM	L	L	L	Z	F3	F2	F1	F0	Z	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	Z	F3 _n	F2 _n	F1 _n	F0 _n	Z	F3	F2	F1	F0
LOAD B	L	L	H	Z	b3	b2	b1	b0	Z	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	Z	b3	b2	b1	b0	Z	Z	Z	Z	Z
LEFT SHIFT LOGICAL	L	H	L	li	F3	F2	F1	F0	QB0	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	li	li	QB3 _n	QB2 _n	QB1 _n	QB0 _n	F3	F2	F1	F0
LEFT SHIFT ARITH	L	H	H	li	F3	F2	F1	F0	QB0	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	li	QB3 _n	li	QB2 _n	QB1 _n	QB0 _n	F3	F2	F1	F0
RIGHT SHIFT LOGICAL	H	L	L	QB3	F3	F2	F1	F0	ri	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	QB2 _n	QB2 _n	QB1 _n	QB0 _n	ri	ri	F3	F2	F1	F0
RIGHT SHIFT ARITH	H	L	H	QB2	F3	F2	F1	F0	ri	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	QB1 _n	QB3 _n	QB1 _n	QB0 _n	ri	ri	F3	F2	F1	F0
HOLD	H	H	L	Z	F3	F2	F1	F0	Z	QA3 ₀	QA2 ₀	QA1 ₀	QA0 ₀	Z	QB3 ₀	QB2 ₀	QB1 ₀	QB0 ₀	Z	F3 ₀	F2 ₀	F1 ₀	F0 ₀
LOAD A	H	H	H	Z	a3	a2	a1	a0	Z	a3	a2	a1	a0	Z	QB3 ₀	QB2 ₀	QB1 ₀	QB0 ₀	Z	Z	Z	Z	Z

H = high level (steady state)

L = low level (steady state)

Z = high impedance (output off)

a₀ ... a₃, b₀ ... b₃ = the level of steady-state condition at I/O 0 thru I/O 3, respectively and intended as A or B input data

F₀ ... F₃ = internal ALU results

QA₀ ... QB₀, F₀ ... F₀ = the level of QA₀ thru QB₃ and F₀ thru F₃, respectively, before the indicated steady-state input conditions were established

QA₀_n ... QB₃_n = the level of QA₀ thru QB₃ before the most recent ↑ transition of the clock

ri, li = the level of steady-state conditions at RI/LO or LI/RO, respectively

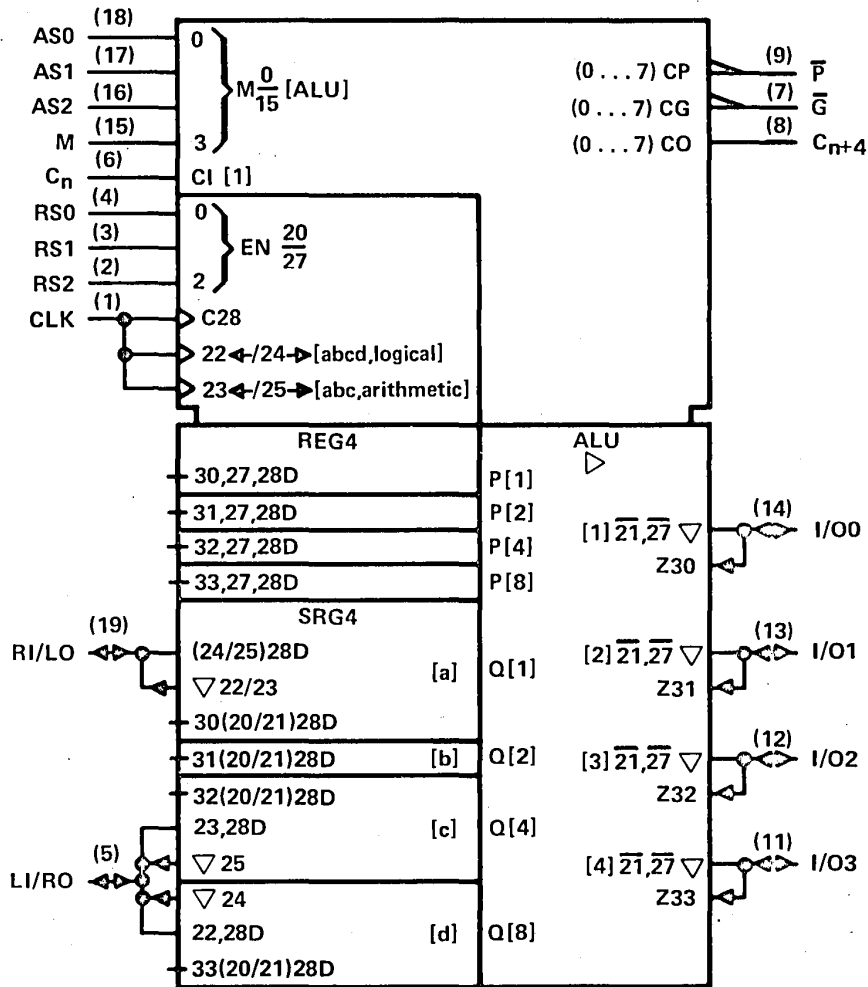


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TYPES SN54LS681, SN74LS681

4-BIT PARALLEL BINARY ACCUMULATORS

logic symbol



Pin numbers shown on logic notation are for DW, J or N packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage	7 V
Operating free-air temperature range: SN54LS681	-55°C to 125°C
SN74LS681	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to the network ground terminal.

3

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TYPES SN54LS681, SN74LS681 4-BIT PARALLEL BINARY ACCUMULATORS

recommended operating conditions

		SN54LS681			SN74LS681			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}		4.5	5	5.5	4.75	5	5.25	V
High-level output current, I_{OH}	LI/RO, I/O, RI/LO	-1			-2.6			mA
	\bar{P} , \bar{G} , C_{n+4}	-0.4			-0.4			mA
Low-level output current, I_{OL}	I/O	12			24			mA
	C_{n+4} , LI/RO, RI/LO	4			8			
	\bar{P}	8			8			
	\bar{G}	16			16			
Clock frequency, f_{clock}		0		20	0		20	MHz
Width of clock pulse, $t_w(\text{clock})$		25			25			ns
Setup time, t_{su}	RS0-RS2 to CLK†	30			30			ns
	Data I/O to CLK†	25			25			
Hold time, t_h		0			0			ns
Operating free-air temperature, T_A		-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	SN54LS681			SN74LS681			UNIT
			MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage	C_n	0.7			0.7			V
		All others	0.7			0.8			
V_{IK}	Input clamp voltage	$V_{CC}=\text{MIN}$, $I_I=-18\text{ mA}$	-1.5			-1.5			V
V_{OH}	High-level output voltage	All I/O	$V_{CC}=\text{MIN}$, $V_{IH}=2\text{ V}$, $V_{IL}=V_{IL\text{ max}}$, $I_{OH}=\text{MAX}$	2.4	3.1	2.4	3.2	V	
		\bar{P} , \bar{G} , C_{n+4}		2.5	3.4	2.7	3.4		
V_{OL}	Low-level output voltage	I/O	$V_{CC}=\text{MAX}$, $V_{IH}=2\text{ V}$, $V_{IL}=V_{IL\text{ max}}$	$I_{OL}=12\text{ mA}$	0.25	0.4	0.25	0.4	V
				$I_{OL}=24\text{ mA}$			0.35	0.5	
		LI/RO, RI/LO, C_{n+4}		$I_{OL}=4\text{ mA}$	0.25	0.4	0.25	0.4	
				$I_{OL}=8\text{ mA}$			0.35	0.5	
		\bar{P}		$I_{OL}=8\text{ mA}$	0.35	0.5	0.35	0.5	
		\bar{G}		$I_{OL}=16\text{ mA}$	0.35	0.5	0.35	0.5	
I_{OZH}	Off-state output current, high-level voltage applied	I/O, LI/RO, RI/LO	$V_{CC}=\text{MAX}$, $V_{IH}=2\text{ V}$, $V_{O}=2.7\text{ V}$, $V_{IL}=V_{IL\text{ max}}$	40			40	µA	
I_{OZL}	Off-state output current, low-level voltage applied	I/O, LI/RO	$V_{CC}=\text{MAX}$, $V_{IH}=2\text{ V}$, $V_{IL}=V_{IL\text{ max}}$, $V_{O}=0.4\text{ V}$	-0.8			-0.8	mA	
		RI/LO		-0.4			-0.4		
I_I	Input current at maximum input voltage	All I/O	$V_{CC}=\text{MAX}$	$V_I=5.5\text{ V}$	0.1			0.1	mA
		C_n		$V_I=7\text{ V}$	0.5			0.5	
		All others			0.1			0.1	
I_{IH}	High-level input current	C_n	$V_{CC}=\text{MAX}$, $V_I=2.7\text{ V}$	100			100	µA	
		All I/O		40			40		
		All others		20			20		
I_{IL}	Low-level input current	C_n	$V_{CC}=\text{MAX}$, $V_I=0.4\text{ V}$	-4			-4	mA	
		I/O, LI/RO		-0.8			-0.8		
		CLK		-0.2			-0.2		
		All others		-0.4			-0.4		
I_{OS}	Short-circuit output current §	I/O	$V_{CC}=\text{MAX}$	-30	-130	-30	-130	mA	
		LI/RO, RI/LO, \bar{P} , \bar{G} , C_{n+4}		-20	-100	-20	-100		
I_{CC}	Supply current	$V_{CC}=\text{MAX}$, RS0 at 4.5 V, All other I/O at 0 V	100	150	100	150	mA		

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operations.

‡ All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

§ Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

3
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TYPES SN54LS681, SN74LS681
4-BIT PARALLEL BINARY ACCUMULATORS

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^\circ C$

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
t_{PLH}	CLOCK †	\bar{P}	$R_L = 667 \Omega$,	$C_L = 45 pF$	25	40	ns		
t_{PHL}					30	45			
t_{PLH}		\bar{G}					26	40	ns
t_{PHL}							27	40	
t_{PLH}		I/O					27	40	ns
t_{PHL}							29	40	
t_{PLH}		C_n+4	$R_L = 2 k\Omega$,	$C_L = 15 pF$	36	55	ns		
t_{PHL}					34	50			
t_{PLH}		LI/RO					25	40	ns
t_{PHL}							23	35	
t_{PLH}		RI/LO					19	30	ns
t_{PHL}							17	30	
t_{PLH}	AS0-AS2	\bar{P}	$R_L = 667 \Omega$,	$C_L = 45 pF$	30	45	ns		
t_{PHL}					30	45			
t_{PLH}		\bar{G}					27	35	ns
t_{PHL}					28	35			
t_{PLH}		I/O			31	45	ns		
t_{PHL}					29	45			
t_{PLH}	C_n+4	$R_L = 2 k\Omega$,	$C_L = 15 pF$	39	55	ns			
t_{PHL}				34	50				
t_{PLH}	C_n	\bar{P}	$R_L = 667 \Omega$,	$C_L = 45 pF$	9	25	ns		
t_{PHL}					9	20			
t_{PLH}		I/O					17	35	ns
t_{PHL}					13	20			
t_{PLH}		C_n+4	$R_L = 2 k\Omega$,	$C_L = 15 pF$	20	30	ns		
t_{PHL}					16	25			
t_{PLH}	MODE	\bar{P}	$R_L = 667 \Omega$,	$C_L = 45 pF$	28	40	ns		
t_{PHL}					29	40			
t_{PLH}		\bar{G}					21	30	ns
t_{PHL}					23	30			
t_{PLH}		I/O			30	45	ns		
t_{PHL}					28	40			
t_{PLH}	C_n+4	$R_L = 2 k\Omega$,	$C_L = 15 pF$	40	60	ns			
t_{PHL}				37	50				
t_{PZH}	RS0-RS2	I/O	$R_L = 667 \Omega$	$C_L = 45 pF$	28	45	ns		
t_{PZL}						28		45	
t_{PHZ}						$C_L = 5 pF$	35	65	ns
t_{PLZ}						39	65		
t_{PZH}			LI/RO	$R_L = 2 k\Omega$	$C_L = 15 pF$	25	40	ns	
t_{PZL}							22		40
t_{PHZ}					$C_L = 5 pF$	21	40	ns	
t_{PLZ}					34	60			
t_{PZH}		RI/LO	$R_L = 2 k\Omega$		$C_L = 15 pF$	22	40	ns	
t_{PZL}							24		40
t_{PHZ}					$C_L = 5 pF$	11	30	ns	
t_{PLZ}					16	40			

† t_{PLH} = Propagation delay time, low-to-high-level input
 t_{PHL} = Propagation delay time, high-to-low-level input
 t_{PZL} = Output enable time to low level

t_{PZH} = Output enable time to high level
 t_{PLZ} = Output disable time from low level
 t_{PHZ} = Output disable time from high level

NOTE 2: See General Information Section for load circuits and voltage waveforms.



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